



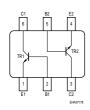
#### **NPN Silicon AF Transistor Arrays**

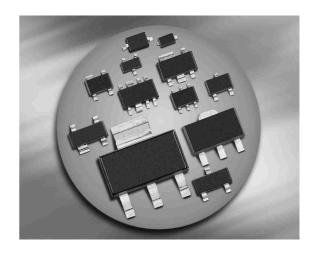
- For AF input stages and driver applications
- High current gain
- Low collector-emitter saturation voltage
- Two (galvanic) internal isolated transistors with good matching in one package
- BC846S / U, BC847S: For orientation in reel see package information below
- Pb-free (RoHS compliant) package
- Qualified according AEC Q101





BC846S BC846U BC847S





Туре	Marking	Pin Configuration					Package	
BC846S	1Ds	1=E1	2=B1	3=C2	4=E2	5=B2	6=C1	SOT363
BC846U	1Ds	1=E1	2=B1	3=C2	4=E2	5=B2	6=C1	SC74
BC847S	1Cs	1=E1	2=B1	3=C2	4=E2	5=B2	6=C1	SOT363

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# BC846S/ BC846U/ BC847S

**Maximum Ratings** 

Parameter	Symbol	Value	Unit
Collector-emitter voltage	$V_{CEO}$		V
BC846S/U		65	
BC847S		45	
Collector-base voltage	$V_{\mathrm{CBO}}$		
BC846S/U		80	
BC847S		50	
Emitter-base voltage	V <sub>EBO</sub>	6	
Collector current	I <sub>C</sub>	100	mA
Peak collector current, $t_p \le 10 \text{ ms}$	I <sub>CM</sub>	200	
Total power dissipation-	P <sub>tot</sub>		mW
<i>T</i> <sub>S</sub> ≤ 115 °C, BC846S, BC847S		250	
<i>T</i> <sub>S</sub> ≤ 118 °C, BC846U		250	
Junction temperature	$T_{ m j}$	150	°C
Storage temperature	T <sub>stg</sub>	-65 150	

#### **Thermal Resistance**

Parameter	Symbol	Value	Unit
Junction - soldering point <sup>1)</sup>	$R_{thJS}$		K/W
BC846S, BC847S		≤ 140	
BC847U		≤ 130	

 $<sup>^{1}</sup>$ For calculation of  $R_{thJA}$  please refer to Application Note AN077 (Thermal Resistance Calculation)

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## BC846S/ BC846U/ BC847S

**Electrical Characteristics** at  $T_A$  = 25°C, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics	, ,			Г	1
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>				V
$I_{\rm C}$ = 10 mA, $I_{\rm B}$ = 0 , BC846S/U		-	65	-	
$I_{\rm C}$ = 10 mA, $I_{\rm B}$ = 0 , BC847S		-	45	-	
Collector-base breakdown voltage	V <sub>(BR)CBO</sub>				
$I_{\rm C}$ = 10 $\mu$ A, $I_{\rm E}$ = 0 , BC846S/U		-	80	-	
$I_{\rm C}$ = 10 $\mu{\rm A},\ I_{\rm E}$ = 0 , BC847S		-	50	-	
Emitter-base breakdown voltage	V <sub>(BR)EBO</sub>	-	6	-	
$I_{\rm E} = 1  \mu A,  I_{\rm C} = 0$					
Collector-base cutoff current	I <sub>CBO</sub>				μA
$V_{\text{CB}} = 45 \text{ V}, I_{\text{E}} = 0$		-	-	0.015	
$V_{\text{CB}}$ = 30 V, $I_{\text{E}}$ = 0 , $T_{\text{A}}$ = 150 °C		-	-	5	
DC current gain-	h <sub>FE</sub>				-
$I_{\rm C}$ = 10 $\mu$ A, $V_{\rm CE}$ = 5 V		-	250	-	
$I_{\rm C}$ = 2 mA, $V_{\rm CE}$ = 5 V		200	290	450	
Collector-emitter saturation voltage <sup>1)</sup>	V <sub>CEsat</sub>				mV
$I_{\rm C}$ = 10 mA, $I_{\rm B}$ = 0.5 mA		-	90	250	
$I_{\rm C}$ = 100 mA, $I_{\rm B}$ = 5 mA		_	200	600	
Base emitter saturation voltage <sup>1)</sup>	V <sub>BEsat</sub>				
$I_{\rm C}$ = 10 mA, $I_{\rm B}$ = 0.5 mA	====	_	700	_	
$I_{\rm C}$ = 100 mA, $I_{\rm B}$ = 5 mA		_	900	_	
Base-emitter voltage <sup>1)</sup>	V <sub>BE(ON)</sub>				
$I_{\rm C}$ = 2 mA, $V_{\rm CE}$ = 5 V		580	660	700	
$I_{\rm C}$ = 10 mA, $V_{\rm CE}$ = 5 V		-	-	770	

<sup>&</sup>lt;sup>1</sup>Pulse test: t < 300µs; D < 2%



## BC846S/ BC846U/ BC847S

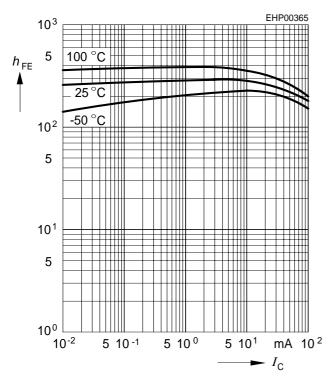
**Electrical Characteristics** at  $T_A = 25$ °C, unless otherwise specified

Parameter	Symbol		Values	Unit	
		min.	typ.	max.	
AC Characteristics					
Transition frequency	$f_{T}$	-	250	-	MHz
$I_{\rm C}$ = 20 mA, $V_{\rm CE}$ = 5 V, $f$ = 100 MHz					
Collector-base capacitance	$C_{cb}$	-	0.95	-	pF
V <sub>CB</sub> = 10 V, f = 1 MHz					
Emitter-base capacitance	C <sub>eb</sub>	-	9	-	
$V_{\text{EB}} = 0.5 \text{ V}, f = 1 \text{ MHz}$					
Short-circuit input impedance	h <sub>11e</sub>	-	4.5	-	kΩ
$I_{\rm C}$ = 2 mA, $V_{\rm CE}$ = 5 V, $f$ = 1 kHz					
Open-circuit reverse voltage transf. ratio	h <sub>12e</sub>	-	2	-	10-4
$I_{\rm C}$ = 2 mA, $V_{\rm CE}$ = 5 V, $f$ = 1 kHz					
Short-circuit forward current transf. ratio	h <sub>21e</sub>	-	330	-	-
$I_{\rm C}$ = 2 mA, $V_{\rm CE}$ = 5 V, $f$ = 1 kHz					
Open-circuit output admittance	h <sub>22e</sub>	-	30	-	μS
$I_{\rm C}$ = 2 mA, $V_{\rm CE}$ = 5 V, $f$ = 1 kHz					
Noise figure	F	-	-	10	dB
$I_{\rm C}$ = 200 $\mu$ A, $V_{\rm CE}$ = 5 V, $f$ = 1 kHz,					
$\Delta f$ = 200 Hz, $R_{S}$ = 2 k $\Omega$					



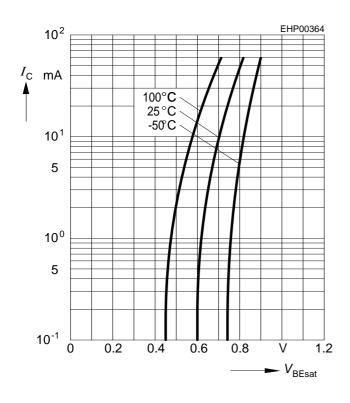
# **DC** current gain $h_{FE} = f(I_C)$

$$V_{CE} = 5 \text{ V}$$



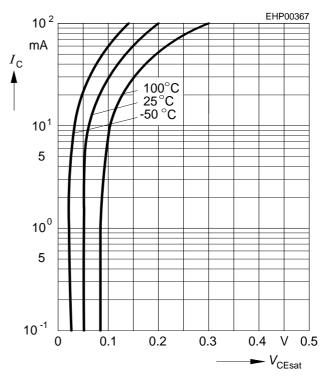
#### **Base-emitter saturation voltage**

$$I_{\rm C} = f(V_{\rm BEsat}), h_{\rm FE} = 20$$



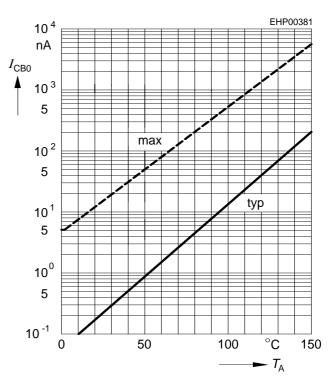
#### Collector-emitter saturation voltage

$$I_{\text{C}} = f(V_{\text{CEsat}}), h_{\text{FE}} = 20$$



# Collector cutoff current $I_{CBO} = f(T_A)$

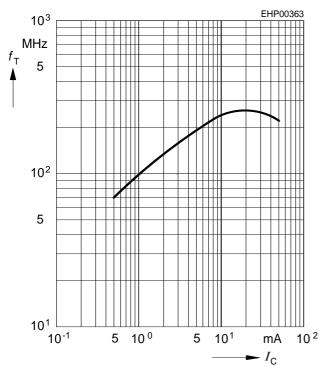
$$V_{\rm CBO}$$
 = 30 V



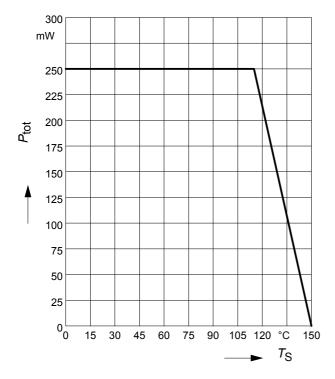


# Transition frequency $f_T = f(I_C)$

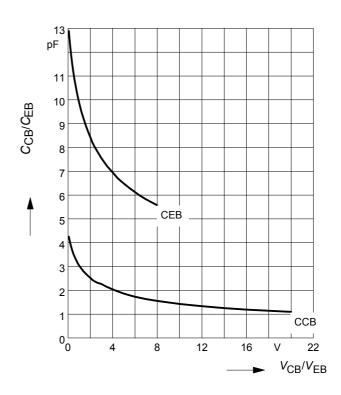
 $V_{CE} = 5 \text{ V}$ 



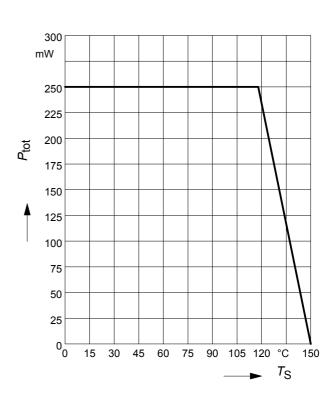
Total power dissipation  $P_{\text{tot}} = f(T_{\text{S}})$  BC846S, BC847S



# Collector-base capacitance $C_{cb} = f(V_{CB})$ Emitter-base capacitance $C_{eb} = f(V_{EB})$

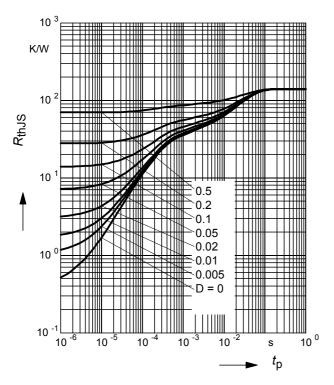


Total power dissipation  $P_{\text{tot}} = f(T_{\text{S}})$  BC846U

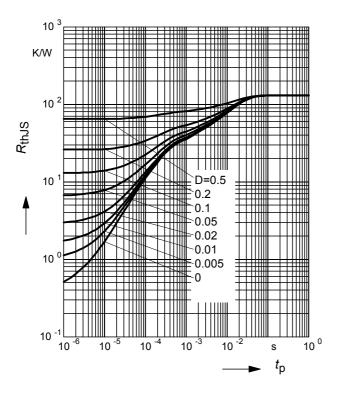




# **Permissible Pulse Load** $R_{thJS} = f(t_p)$ BC846S, BC847S

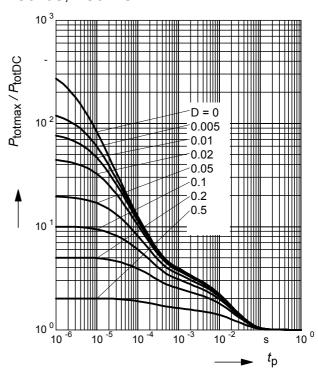


# **Permissible Puls Load** $R_{thJS} = f(t_p)$ BC846U



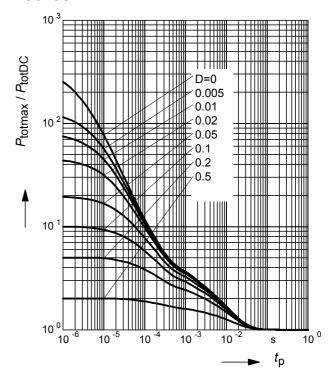
#### **Permissible Pulse Load**

 $P_{\text{totmax}}/P_{\text{totDC}} = f(t_{\text{p}})$ BC846S, BC847S



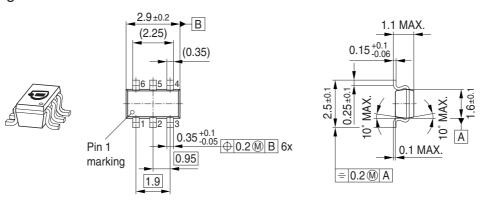
#### **Permissible Pulse Load**

 $P_{\text{totmax}}/P_{\text{totDC}} = f(t_{\text{p}})$ BC846U

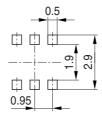




#### Package Outline

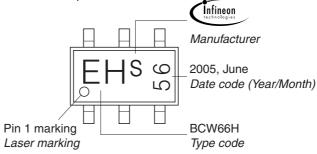


#### Foot Print



# Marking Layout (Example)

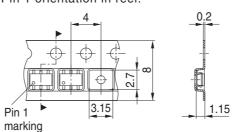
Small variations in positioning of Date code, Type code and Manufacture are possible.



# Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel

For symmetric types no defined Pin 1 orientation in reel.

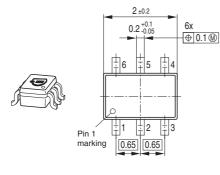


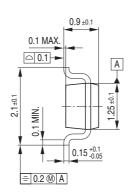
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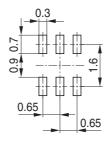
# Package SOT363 BC846S/ BC846U/ BC847S

#### Package Outline



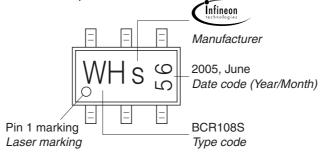


#### Foot Print



## Marking Layout (Example)

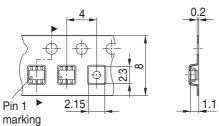
Small variations in positioning of Date code, Type code and Manufacture are possible.



# Standard Packing

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